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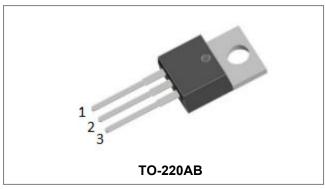








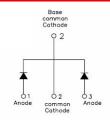
### MBR2060CTL SCHOTTKY RECTIFIER



#### **Features**

- 125°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- · mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Circuit Diagram**



#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	-	60	V
DC Blocking Voltage  Average Rectified Forward Current	V <sub>R</sub>	50% duty cycle @Tc=80°C, rectangular wave form	10(Per Leg) 20(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>C</sub> = 25 °C	150	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 10A, Pulse, T <sub>J</sub> = 25 °C	0.65	0.69	V
	V <sub>F2</sub>	@ 10A, Pulse, T <sub>J</sub> = 125 °C	0.60	0.65	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$	0.008	1.0	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	3	40	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C f_{SiG} = 1MHz$	260	400	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

Pulse width < 300 µs, duty cycle < 2%

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### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +125	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	2.3	°C/W
Typical Thermal Resistance Case to Heat Sink	R <sub>θCS</sub>	Mounting surface, smooth and greased(only for TO-220)	0.50	°C/W
Approximate Weight	wt	-	2	g

### **Ratings and Characteristics Curves**

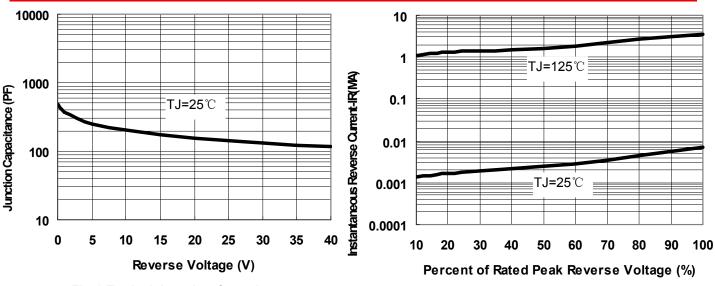


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

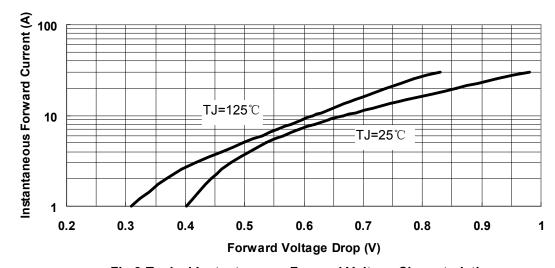


Fig.3-Typical Instantaneous Forward Voltage Characteristics

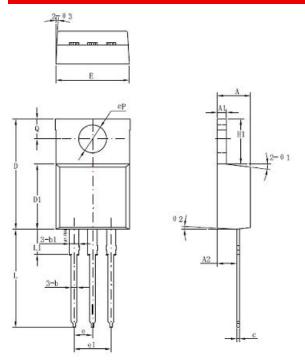
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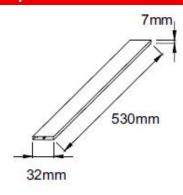


#### **Mechanical Dimensions TO-220AB**



	Dimensions in			
Symbol	millimeters			
	Min	Typical	Max	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

### **Tube Specification**



### **Marking Diagram**



Where XXXXX is YYWWL

 MBR
 = Device Type

 20
 = Forward Current (20A)

 60
 = Reverse Voltage(60V)

 CTL
 = Configuration

 SSG
 = SSG

SSG = SSG YY = Year WW = Week L = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
MBR2060CTL	TO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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